



High-end Power Semiconductor Manufacturer

ZP900A 7500-8500V Standard Rectifier Diode

- High power cycling capability
- Low on-state and switching losses
- Optimized for line frequency rectifiers
- Designed for traction and industrial applications



Average forward current		I_{FAV}		910 A			
Repetitive peak reverse voltage		V_{RRM}		7500 – 8500 V			
V_{RRM} , V	7500	7600	7800	8000	8200	8400	8500
Voltage code	75	76	78	80	82	84	85
T_j , °C	-40 – 160						

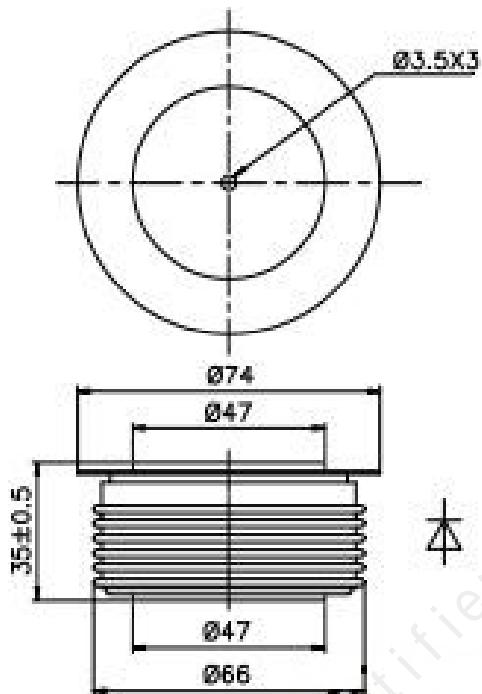
MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions	
ON-STATE					
I_{FAV}	Average forward current	A	910	$T_c=100$ °C; Double side cooled; 180° half-sine wave; 50 Hz	
I_{FRMS}	RMS forward current	A	1429	$T_c=100$ °C	
I_{FSM}	Surge forward current	kA	16.5	$T_j=T_{j\max}$	180° half-sine wave; ($t_p=10$ ms); $V_R=0$ V
I^2t	Safety factor	$A^2s \cdot 10^4$	136	$T_j=T_{j\max}$	180° half-sine wave; ($t_p=10$ ms)
BLOCKING					
V_{RRM}	Repetitive peak reverse voltages	V	7500-8500	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave	
V_{RSM}	Non-repetitive peak reverse voltages	V	8000-9000	$T_j=25, 150$ °C; $I_{RRM} \leq 150$ mA; $V_R=V_{RRM}$; $t_p=10$ ms	
THERMAL					
T_{stg}	Storage temperature	°C	-40-160		
T_j	Operating junction temperature	°C	-40-150		
MECHANICAL					
F	Mounting force	kN	22.0		

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	1.85	$T_j=25\text{ }^\circ\text{C}; I_{TM}=1500\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	1.25	
r_T	Forward slope resistance, max	$\text{m}\Omega$	0.550	$T_j=T_{j\max}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	150	$T_j=T_{j\max}; V_R=V_{RRM}$
THERMAL				
R_{thjc}	Thermal resistance, junction to case, max	$^\circ\text{C}/\text{W}$	0.020	
R_{thck}	Thermal resistance, case to heatsink, max	$^\circ\text{C}/\text{W}$	0.005	
MECHANICAL				
w	Weight, typ	g	600	

OVERALL DIMENSIONS



ZT55DT

All dimensions in millimeters

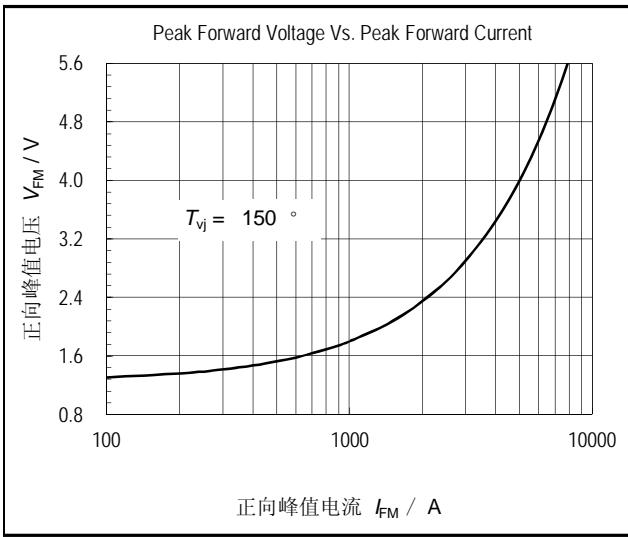


图1. 正向伏安特性曲线

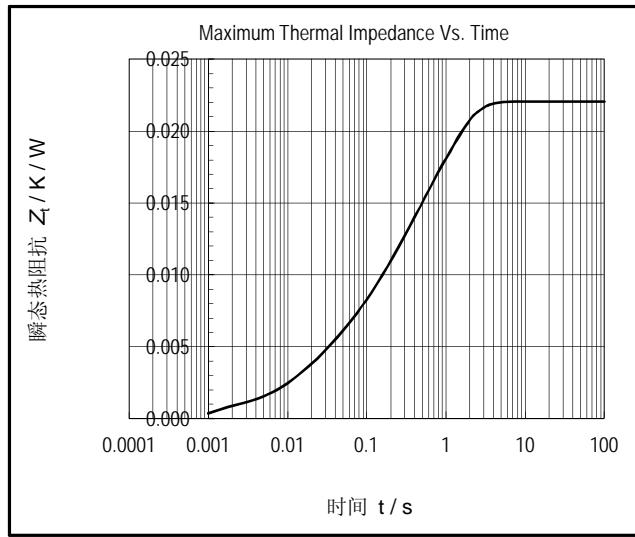


图2. 瞬态热阻抗曲线

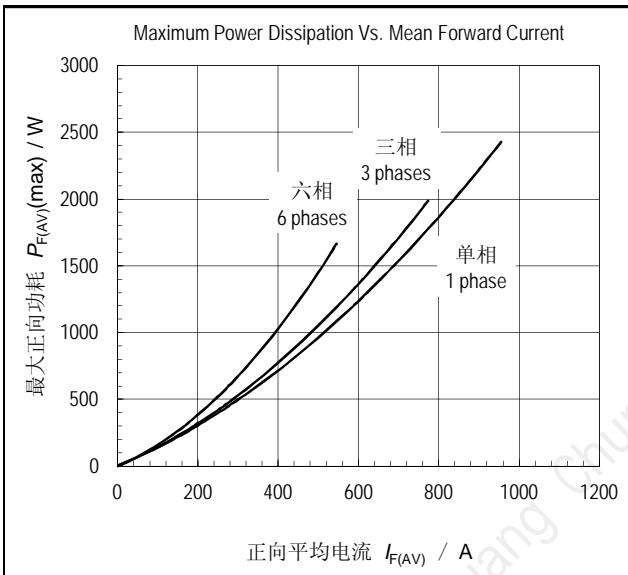


图3. 最大正向功耗与正向平均电流的关系曲线

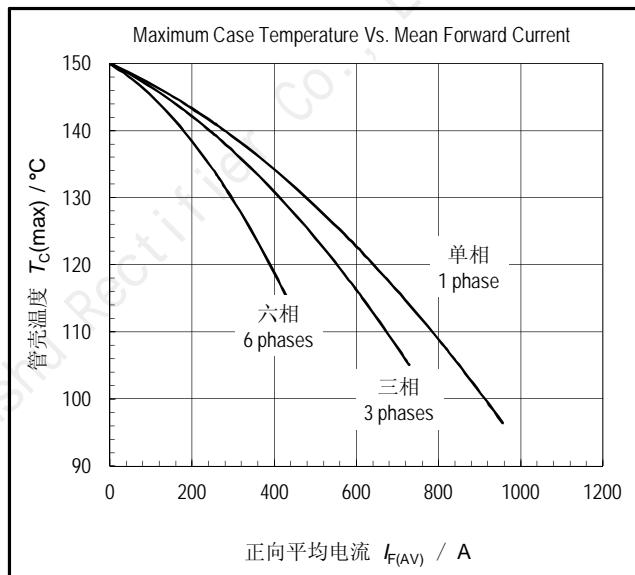


图4. 管壳温度与正向平均电流的关系曲线

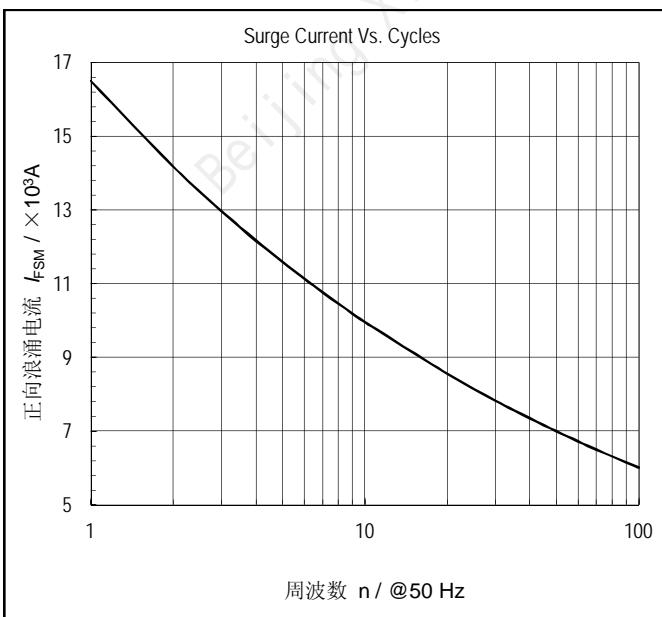


图5. 正向浪涌电流与周波数的关系曲线

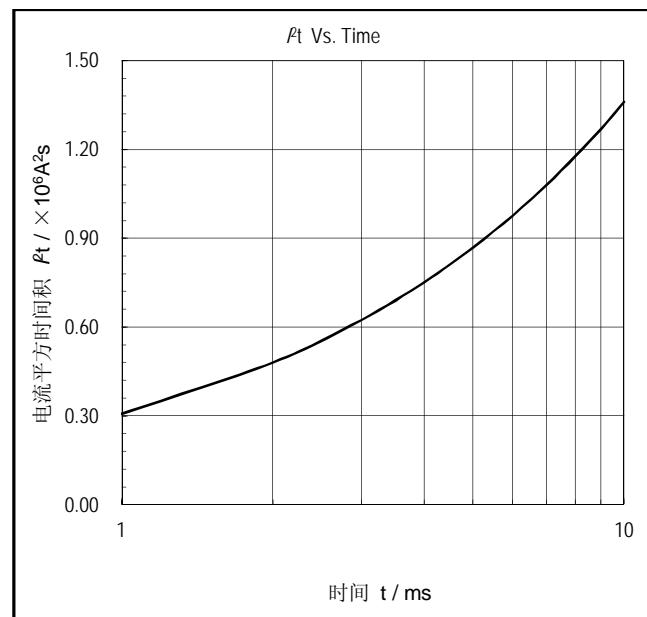


图6. I^2t 特性曲线